



DUAL PNP SURFACE MOUNT SMALL SIGNAL TRANSISTOR

Features

Ideally Suited for Automatic Insertion
For Switching and AF Amplifier Applications
Ultra-Small Surface Mount Package
Lead Free/RoHS Compliant (Note 2)

Mechanical Data

Case: SOT-363

Case Material: Molded Plastic. UL Flammability

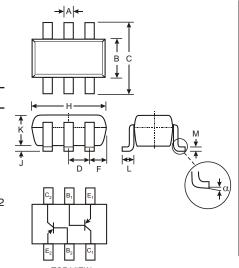
Classification Rating 94V-0

Moisture Sensitivity: Level 1 per J-STD-020C Terminals: Solderable per MIL-STD-202, Method 208 Lead Free Plating (Matte Tin Finish annealed over Alloy 42

leadframe).

Terminal Connections: See Diagram Marking: K3W (See Page 3) Ordering Information (See Page 3)

Weight: 0.006 grams



	SOT-363						
Dim	Min	Max					
Α	0.10	0.30					
В	1.15	1.35					
С	2.00 2.20						
D	0.65 N	Nominal					
F	0.30 0.40						
Н	1.80	2.20					
J	0.10						
K	0.90	1.00					
L	0.25	0.40					
М	0.10	0.25					
	0	8°					
All Din	nensions	in mm					

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Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-50	V
Collector-Emitter Voltage	V _{CEO}	-45	V
Emitter-Base Voltage	V _{EBO}	-5.0	V
Collector Current (Note 1)	I _C	-100	mA
Peak Collector Current (Note 1)	Ісм	-200	mA
Peak Base Current (Note 1)	I _{BM}	-200	mA
Power Dissipation at T _{SB} = 50°C (Note 1)	Pd	200	mW
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +125	°C

Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

2. No purposefully added lead.



Electrical Characteristics @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
DC Current Gain (Note 3)	h _{FE}	220	_	475	_	$V_{CE} = -5.0V, I_{C} = -2.0mA$
Thermal Resistance, Junction to Ambient Air (Note 1)	R JA	_	_	625	°C/W	Note 1
Collector-Emitter Saturation Voltage (Note 3)	V _{CE} (SAT)	_	_	-100 -400	mV	I _C = -10mA, I _B = -0.5mA I _C = -100mA, I _B = -5.0mA
Base-Emitter Saturation Voltage (Note 3)	V _{BE(SAT)}	_	-700	_	mV	I _C = -10mA, I _B = -0.5mA
Base-Emitter Voltage (Note 3)	V _{BE}	-580	-665	-750	mV	V _{CE} = -5.0V, I _C = -2.0mA
Collector Cutoff Current	I _{CBO}	_	_	-15 -4.0	nΑ μΑ	$V_{CB} = -30V, I_E = 0$ $V_{CB} = -30V, T_j = 150$ °C
Emitter Cutoff Current	I _{EBO}	_	_	-100	nA	V _{EB} = -5.0V, I _C = 0
Gain Bandwidth Product	f⊤	100	_	_	MHz	V _{CE} = -5.0V, I _C = -10mA, f = 100MHz
Collector-Base Capacitance	C _{CBO}	_	_	3	pF	V _{CB} = -10V, f = 1.0MHz
Emitter-Base Capacitance	C _{EBO}	_	11	_	pF	V _{EB} = -0.5V, f = 1.0MHz

Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

- 2. No purposefully added lead.
- 3. Short duration test pulse used to minimize self-heating effect.

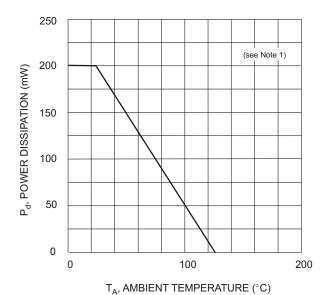
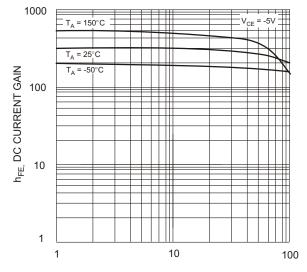


Fig. 1, Power Derating Curve

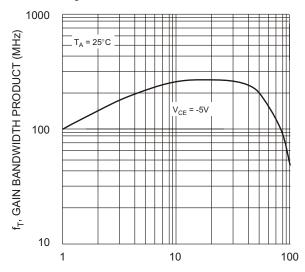
0.5

| O.4 | O.4 | O.4 | O.5 | O.4 | O.5 |

I_C, COLLECTOR CURRENT (mA)
Fig. 3, Collector Saturation Voltage vs Collector Current



I_C, COLLECTOR CURRENT (mA) Fig. 2, DC Current Gain vs Collector Current



 $\label{eq:lc} {\rm I_C,\,COLLECTOR\,\,CURRENT\,\,(mA)}$ Fig. 4, Gain Bandwidth Product vs Collector Current

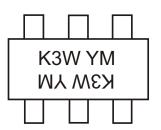


Ordering Information (Note 4)

Device	Packaging	Shipping
BC857BS-7-F	SOT-363	3000/Tape & Reel

Notes: 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



K3W = Product Type Marking Code YM = Date Code Marking Y = Year ex: N = 2002 M = Month ex: 9 = September

Date Code Key

	Year	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Ī	Code	N	Р	R	S	Т	U	V	W	Х	Υ	Z

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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